

TOSHIBA

TOSHIBA Original CMOS 16-Bit Microcontroller

TLCS-900/H Series

TMP95PW64FG

Not Recommended
for New Design

TOSHIBA CORPORATION

Semiconductor Company

Preface

Thank you very much for making use of Toshiba microcomputer LSIs.
Before use this LSI, refer the section, "Points of Note and Restrictions".
Especially, take care below cautions.

****CAUTION****

How to release the HALT mode

Usually, interrupts can release all halts status. However, the interrupts = ($\overline{\text{NMI}}$, INT0), which can release the HALT mode may not be able to do so if they are input during the period CPU is shifting to the HALT mode (for about 3 clocks of X1) with IDLE1 or STOP mode (IDLE2 is not applicable to this case). (In this case, an interrupt request is kept on hold internally.)

If another interrupt is generated after it has shifted to HALT mode completely, halt status can be released without difficulty. The priority of this interrupt is compare with that of the interrupt kept on hold internally, and the interrupt with higher priority is handled first followed by the other interrupt.

Document Change Notification

The purpose of this notification is to inform customers about the launch of the Pb-free version of the device. The introduction of a Pb-free replacement affects the datasheet. Please understand that this notification is intended as a substitute for a revision of the datasheet.

Changes to the datasheet may include the following, though not all of them may apply to this particular device.

1. Part number

Example: TMPxxxxxF → TMPxxxxxFG

All references to the previous part number were left unchanged in body text. The new part number is indicated on the prelims pages (cover page and this notification).

2. Package code and package dimensions

Example: LQFP100-P-1414-0.50C → LQFP100-P-1414-0.50F

All references to the previous package code and package dimensions were left unchanged in body text. The new ones are indicated on the prelims pages.

3. Addition of notes on lead solderability

Now that the device is Pb-free, notes on lead solderability have been added.

4. RESTRICTIONS ON PRODUCT USE

The previous (obsolete) provision might be left unchanged on page 1 of body text. A new replacement is included on the next page.

5. Publication date of the datasheet

The publication date at the lower right corner of the prelims pages applies to the new device.

1. Part number

Previous Part Number (in Body Text)	New Part Number
TMP95PW64F	TMP95PW64FG

2. Package code and dimensions

Previous Package Code (in Body Text)	New Package Code
P-LQFP100-1414-0.50F	LQFP100-P-1414-0.50F

*: For the dimensions of the new package, see the attached Package Dimensions diagram.

3. Addition of notes on lead solderability

The following solderability test is conducted on the new device.

Solderability of lead free products

Test Parameter	Test Condition	Note
Solderability	Use of Sn-37Pb solder Bath Solder bath temperature = 230°C, Dipping time = 5 seconds The number of times = one, Use of R-type flux	Pass: Solderability rate until forming ≥ 95%
	Use of Sn-3.0Ag-0.5Cu solder bath Solder bath temperature = 245°C, Dipping time = 5 seconds The number of times = one, Use of R-type flux (use of lead free)	

4. RESTRICTIONS ON PRODUCT USE

The following replaces the “RESTRICTIONS ON PRODUCT USE” on page 1 of body text.

RESTRICTIONS ON PRODUCT USE

20070701-EN

<ul style="list-style-type: none"> The information contained herein is subject to change without notice. TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc. The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk. The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations. The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patents or other rights of TOSHIBA or the third parties. Please contact your sales representative for product-by-product details in this document regarding RoHS compatibility. Please use these products in this document in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses occurring as a result of noncompliance with applicable laws and regulations. For a discussion of how the reliability of microcontrollers can be predicted, please refer to Section 1.3 of the chapter entitled Quality and Reliability Assurance/Handling Precautions.

5. Publication date of the datasheet

The publication date of this datasheet is printed at the lower right corner of this notification.

CMOS 16-Bit Microcontrollers

TMP95PW64F

1. Outline and Features

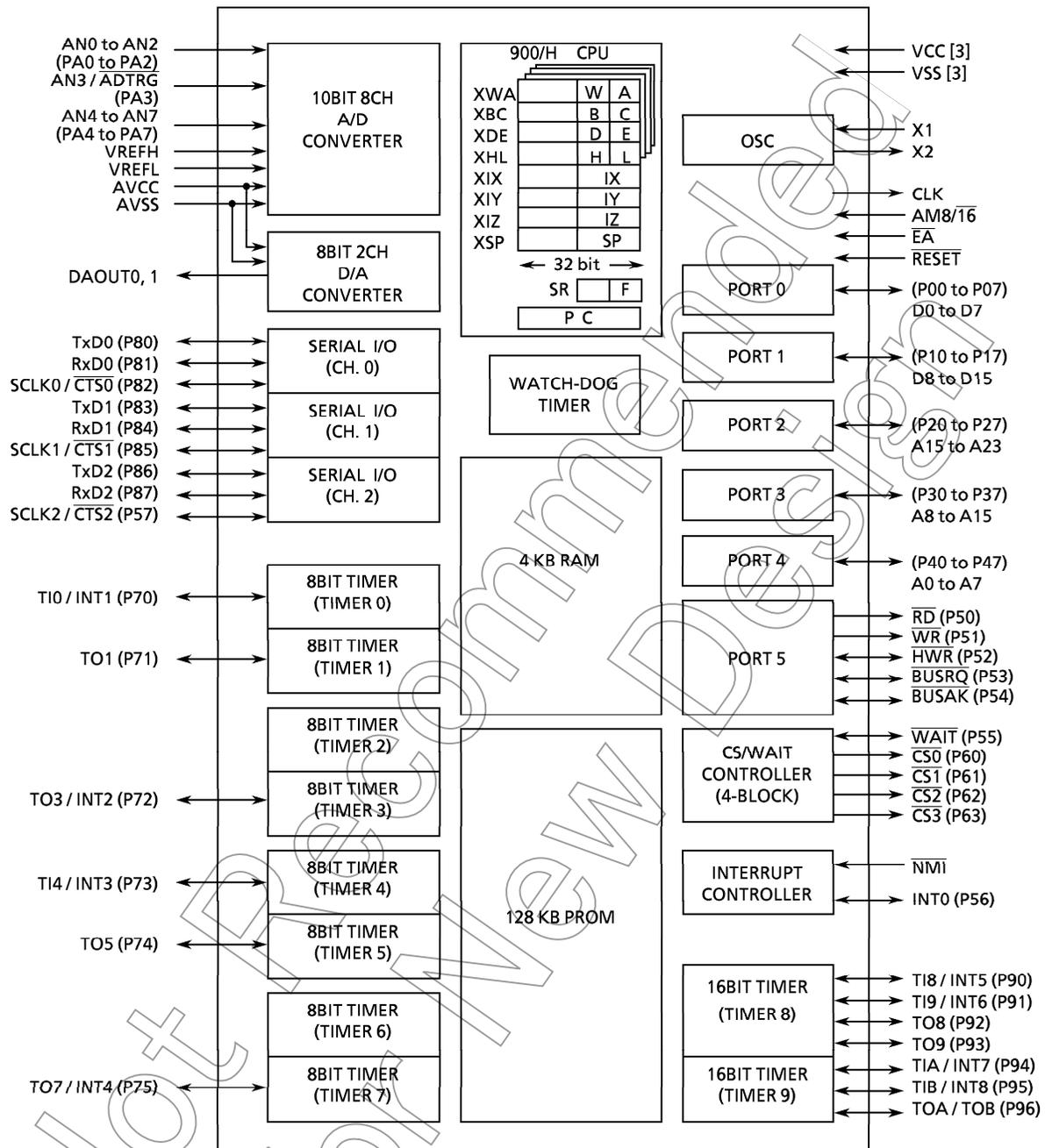
TMP95PW64 is an LSI for TMP95CW64 system evaluation. TMP95PW64 incorporates a 128K-byte one-time PROM. With an adapter socket, the user can write/verify data in the TMP95PW64's PROM using a general-purpose EPROM writer.

TMP95PW64 is pin-compatible with TMP95CW64, which incorporates a mask ROM. To achieve the same operations as TMP95CW64, write program data to the internal PROM.

Product Name	ROM	RAM	Package	Adapter Socket
TMP95PW64F	OTP 128 Kbyte	4 Kbyte	P-LQFP100-1414-0.50F	BM11129

000707EBP1

- For a discussion of how the reliability of microcontrollers can be predicted, please refer to Section 1.3 of the chapter entitled Quality and Reliability Assurance/ Handling Precautions.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.



Note: After a reset, functions in parentheses () are selected for the shared pins.

Figure 1 TMP95PW64 Block Diagram

2. Pin Assignment and Pin Functions

This section shows the TMP95PW64F pin assignment, and the names and an outline of the functions of the input/output pins.

2.1 Pin Assignment Diagram

Figure 2.1 is a pin assignment diagram for TMP95PW64F.

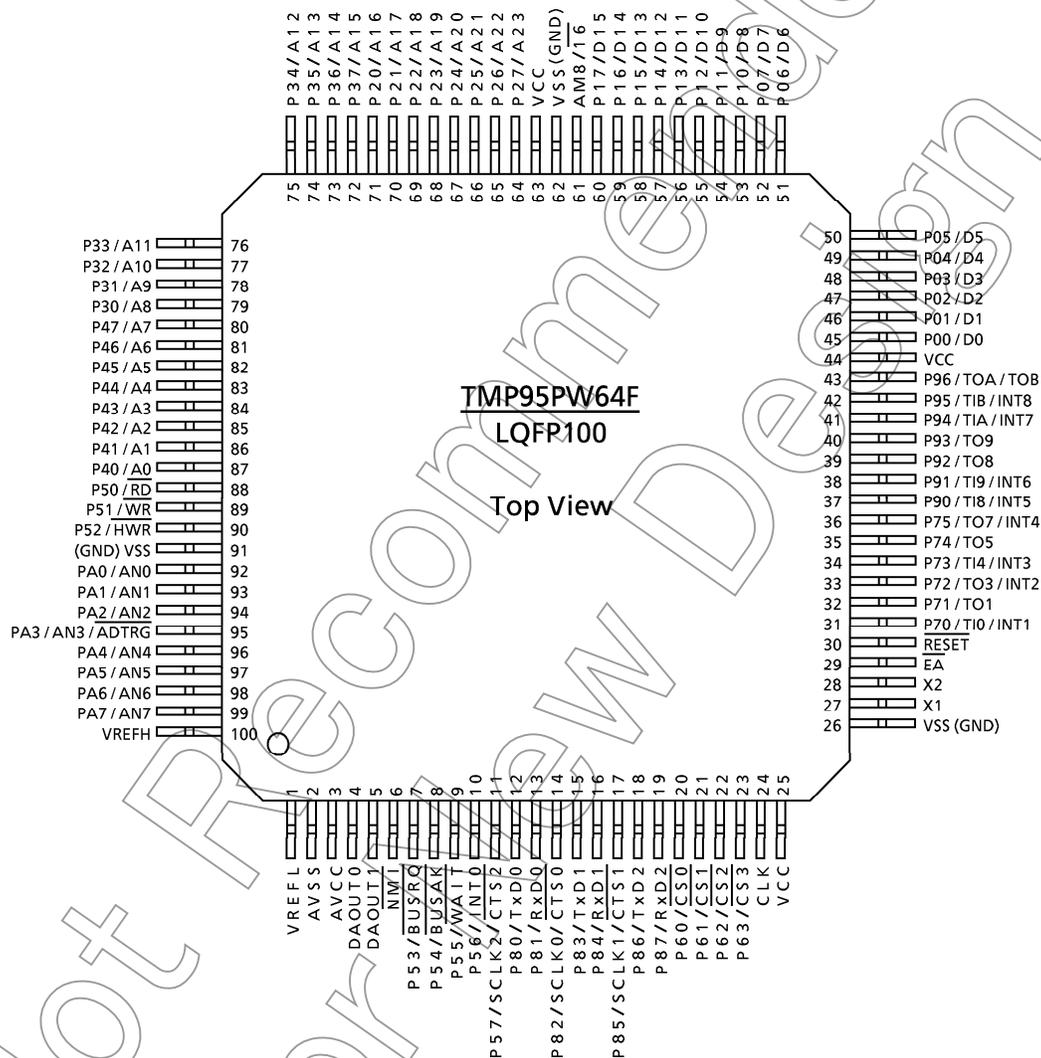


Figure 2.1 Pin Allocation Diagram (100-Pin LQFP)

2.2 Pin Names and Functions

TMP95PW64 has an MCU mode and a PROM mode.

(1) Pin Names and Functions in MCU Mode

Table 2.2 (1) lists the names and functions of the input/output pins.

Table 2.2 Pin Names and Functions (1/4)

Pin Name	Number of Pins	Input/Output	Function
P00 to P07 / D0 to D7	8	Input/output	Port 0: I/O port. Input or output specifiable in units of bits
		Input/output	Data: Data bus 0 to 7
P10 to P17 / D8 to D15	8	Input/output	Port 1: I/O port. Input or output specifiable in units of bits
		Input/output	Data: Data bus 8 to 15
P20 to P27 / A16 to A23	8	Input/output	Port 2: I/O port. Input or output specifiable in units of bits
		Output	Address: Address bus 16 to 23
P30 to P37 / A8 to A15	8	Input/output	Port 3: I/O port. Input or output specifiable in units of bits
		Output	Address: Address bus 8 to 15
P40 to P47 / A0 to A7	8	Input/output	Port 4: I/O port. Input or output specifiable in units of bits
		Output	Address: Address bus 0 to 7
P50 / \overline{RD}	1	Output	Port 50: Output-only port
		Output	Read: Outputs strobe signal to read external memory (setting P5 <P50> = 0 and P5FC <P50F> = 1 outputs strobe signal at all read timings)
P51 / \overline{WR}	1	Output	Port 51: Output-only port.
		Output	Write: Outputs strobe signal to write data on pins D0 to D7
P52 / \overline{HWR}	1	Input/output	Port 52: I/O port (with built-in pull-up resistor)
		Output	Upper write: Outputs strobe signal to write data on pins D8 to D15
P53 / \overline{BUSRQ}	1	Input/output	Port 53: I/O port (with built-in pull-up resistor)
		Input	Bus request: Input pin to request external bus release
P54 / \overline{BUSAK}	1	Input/output	Port 54: I/O port (with built-in pull-up resistor)
		Output	Bus acknowledge: Output pin to acknowledge that CPU received \overline{BUSRQ} and released external bus.
P55 / \overline{WAIT}	1	Input/output	Port 55: I/O port (with built-in pull up resistor)
		Input	Wait: Buswait request pin for CPU (Effective when 1 + N WAIT mode, or 0 + N WAIT mode. Set using chipselect/wait control register.)
P56 / $\overline{INT0}$	1	Input/output	Port 56: I/O port (with built-in pull-up resistor)
		Input	Interrupt request pin 0: Interrupt request pin with programmable level/rising edge. 

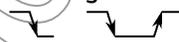
Table 2.2 Pin Names and Functions (2/4)

Pin Name	Number of Pins	Input/Output	Function
P57 /SCLK2 /CTS2	1	Input/output	Port 57: I/O port (with built-in pull-up resistor)
		Input/output	Serial clock input/output 2
		Input	Serial data ready to send 2 (Clear-to-send)
P60 /CS0	1	Output	Port 60: Output-only port
		Output	Chip select 0: Outputs 0 if address is within specified address range
P61 /CS1	1	Output	Port 61: Output-only port
		Output	Chip select 1: Outputs 0 if address is within specified address range
P62 /CS2	1	Output	Port 62: Output-only port
		Output	Chip select 2: Outputs 0 if address is within specified address range
P63 /CS3	1	Output	Port 63: Output-only port
		Output	Chip select 3: Outputs 0 if address is within specified address range
P70 /TI0 /INT1	1	Input/output	Port 70: I/O port
		Input	Timer input 0: Input pin for timer 0
		Input	Interrupt request pin 1: Rising-edge interrupt request pin 
P71 /TO1	1	Input/output	Port 71: I/O port
		Output	Timer output 1: Output pin for timer 0 or 1
P72 /TO3 /INT2	1	Input/output	Port 72: I/O port
		Output	Timer output 3: Output pin for timer 2 or 3
		Input	Interrupt request pin 2: Rising-edge interrupt request pin 
P73 /TI4 /INT3	1	Input/output	Port 73: I/O port
		Input	Timer input 4: Input pin for timer 4
		Input	Interrupt request pin 3: Rising-edge interrupt request pin 
P74 /TO5	1	Input/output	Port 74: I/O port
		Output	Timer output 5: Output pin for timer 4 or 5
P75 /TO7 /INT4	1	Input/output	Port 75: I/O port
		Output	Timer output 7: Output pin for timer 6 or 7
		Input	Interrupt request pin 4: Rising-edge interrupt request pin 
P80 /TxD0	1	Input/output	Port 80: I/O port (with built-in pull-up resistor)
		Output	Serial transmission data 0
P81 /RxD0	1	Input/output	Port 81: I/O port (with built-in pull-up resistor)
		Input	Serial receive data 0
P82 /SCLK0 /CTS0	1	Input/output	Port 82: I/O port (with built-in pull-up resistor)
		Input/output	Serial clock input/output 0
		Input	Serial data ready to send 0 (Clear-to-send)

Table 2.2 Pin Names and Functions (3/4)

Pin Name	Number of Pins	Input/Output	Function
P83 /TxD1	1	Input/output	Port 83: I/O port (with built-in pull-up resistor)
		Output	Serial transmission data 1
P84 /RxD1	1	Input/output	Port 84: I/O port (with built-in pull-up resistor)
		Input	Serial receive data 1
P85 /SCLK1 / $\overline{\text{CTS1}}$	1	Input/output	Port 85: I/O port (with built-in pull-up resistor)
		Input/output	Serial clock input/output 1
		Input	Serial data ready to send 1 (Clear-to-send)
P86 /TxD2	1	Input/output	Port 86: I/O port (with built-in pull-up resistor)
		Output	Serial transmission data 2
P87 /RxD2	1	Input/output	Port 87: I/O port (with built-in pull-up resistor)
		Input	Serial receive data 2
P90 /TI8 /INT5	1	Input/output	Port 90: I/O port
		Input	Timer input 8: Input pin for timer 8
		Input	Interrupt request pin 5: Interrupt request pin with programmable rising/falling edge 
P91 /TI9 /INT6	1	Input/output	Port 91: I/O port
		Input	Timer input 9: Input pin for timer 8
		Input	Interrupt request pin 6: Rising edge interrupt request pin 
P92 /TO8	1	Input/output	Port 92: I/O port
		Output	Timer output 8: Output pin for timer 8
P93 /TO9	1	Input/output	Port 93: I/O port
		Output	Timer output 9: Output pin for timer 8
P94 /TIA /INT7	1	Input/output	Port 94: I/O port
		Input	Timer input A: Input pin for timer 9
		Input	Interrupt request pin 7: Interrupt request pin with programmable rising/falling edge 
P95 /TIB /INT8	1	Input/output	Port 95: I/O port
		Input	Timer input B: Input pin for timer 9
		Input	Interrupt request pin 8: Rising edge interrupt request pin 
P96 /TOA /TOB	1	Input/output	Port 96: I/O port
		Output	Timer input A: Output pin for timer 9
		Output	Timer input B: Output pin for timer 9
PA0 to PA2 /AN0 to AN2	3	Input	Port A0 to A2: Input-only port
		Input	Analog input 0 to 2: A/D converter input pins
PA3 /AN3 /ADTRG	1	Input	Port A3: Input-only port
		Input	Analog input 3: A/D converter input pin
		Input	External start trigger

Table 2.2 Pin Names and Functions (4/4)

Pin Name	Number of Pins	Input/Output	Function
PA4 to PA7 / AN4 to AN7	4	Input	Port A4 to A7: Input-only port
		Input	Analog input 4 to 7: A/D converter input pins
DAOUT0	1	Output	D/A output 0: D/A converter 0 output pin
DAOUT1	1	Output	D/A output 1: D/A converter 1 output pin
NMI	1	Input	Non-maskable interrupt request pin: Interrupt request pin with programmable falling edge or both falling and rising edge 
CLK	1	Output	Clock output: Outputs external clock divided by 4. Pulled up during reset.
\overline{EA}	1	Input	External access: Connect to VCC.
AM8 / $\overline{16}$	1	Input	Address mode: External data bus width select pin. Connect this pin to VCC. Data bus width at external access can be set by chip select/wait control register.
\overline{RESET}	1	Input	Reset: Initializes TMP95PW64 (with built-in pull-up resistor)
VREFH	1	Input	Reference voltage input pin for A/D converter (high)
VREFL	1	Input	Reference voltage input pin for A/D converter (low)
AVCC	1		Power supply pin for A/D converter and reference voltage input pin for D/A converter: Connect to power supply
AVSS	1		GND pin for A/D converter and reference voltage input pin for D/A converter: Connect to GND
X1 / X2	2	Input/output	Oscillator connecting pin
VCC	3		Collector supply pin: Connect all VCC pins to power supply
VSS	3		GND pin: Connect all VSS pins to GND (0 V)

Note: Software can be used to turn off the resistance of pull-up pins with resistors (except for the RESET pin).

(2) PROM Mode Pin Functions and Pin Processing

Tables 2.2 (2) and (3) show the names and functions of the input/output pins, and the pin processing.

Table 2.2 (2) Pin Names and Functions

Pin Function Name	Number of Pins	Input/Output	Function	Pin Name (In MCU Mode)
A7 to A0	8	Input	Program memory address input	P20 to P27
A15 to A8	8			P17 to P10
A16	1			P34
D7 to D0	8	Input/output	Program memory data input/output	P07 to P00
\overline{CE}	1	Input	Chip enable input	P35
\overline{OE}	1	Input	Output control input	P37
\overline{PGM}	1	Input	Program control input	P36
VPP	1	Power supply	12.75 V / 5 V (program power supply)	EA
VCC	4	Power supply	6.25 V / 5 V	VCC, AVCC
VSS	4	Power supply	0 V	VSS, AVSS

Table 2.2 (3) Pin Names and Pin Processing

Pin Name	Number of Pins	Input/Output	Pin Processing
P33	1	Input	Fixed to low level (SECURITY pin)
\overline{RESET}	1	Input	Fixed to low level (set to PROM mode)
CLK	1	Input	
X1	1	Input	Connect oscillator and set to self-oscillation
X2	1	Output	
P32 to P30 P47 to P40 P57 to P52 P75 to P70 P87 to P80 P96 to P90 PA7 to PA0 AM8/16 NMI	48	Input	Fixed to high level
P51 to P50 P63 to P60	6	Output	Open
VREFH	1	Input	
VREFL	1		

3. Operation

The following describes the structure and operation of the TMP95PW64 hardware.

In TMP95PW64, the internal ROM of TMP95CW64 is replaced by an internal PROM. Otherwise, TMP95PW64 is structurally and operationally identical to TMP95CW64. Accordingly, for functions not described here, see the TMP95CW64 section of the manual. TMP95PW64 supports MCU operating mode and PROM operating mode.

3.1 MCU Mode

(1) Setting and Function

Opening the CLK pin (setting to output) sets MCU mode.

In MCU mode, TMP95PW64 operates the same as TMP95CW64.

(2) Memory Map

Figure 3.1 shows the memory map in MCU mode and the CPU access area in each addressing mode.

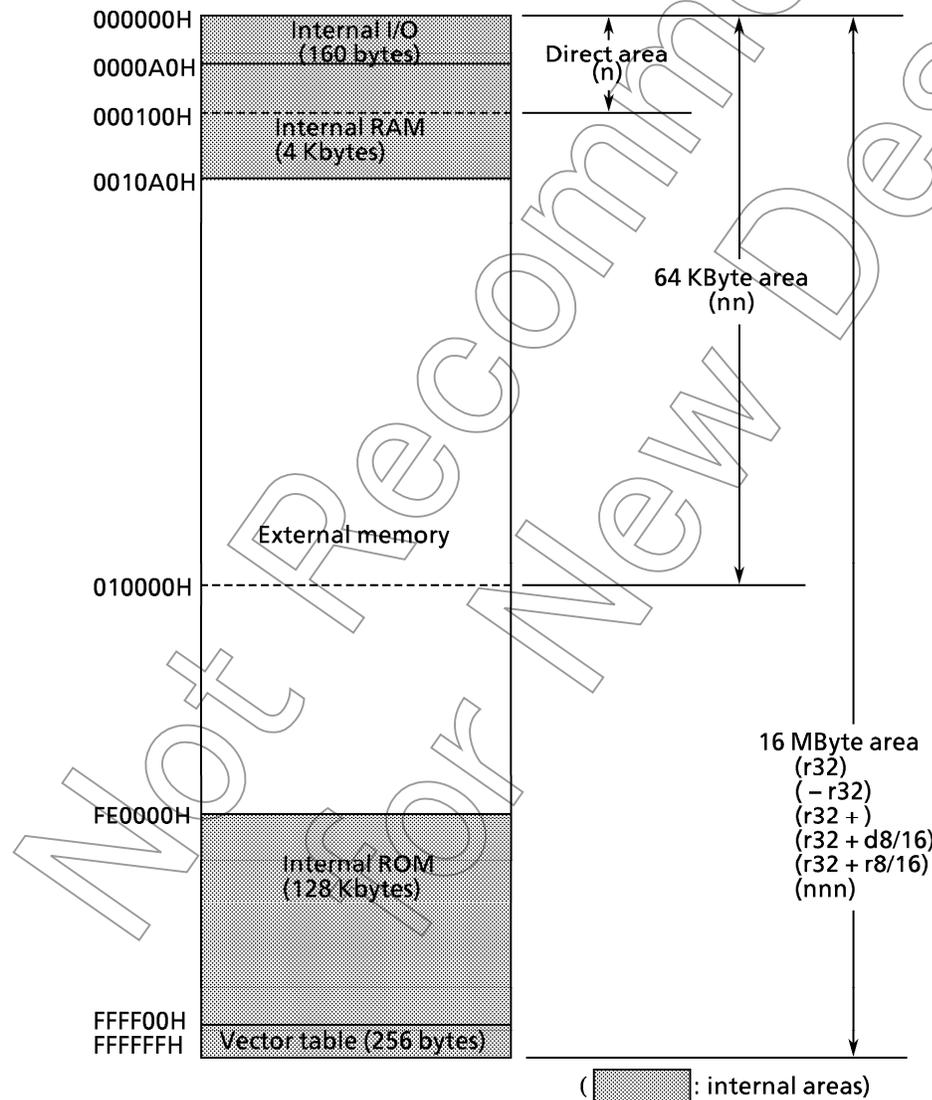


Figure 3.1 TMP95PW64 Memory Map

3.2 PROM Mode

(1) Setting and Functions

To set PROM mode, set the $\overline{\text{RESET}}$ and CLK pins to low level.

After PROM mode is set, applying $V_{CC} = 6.25\text{ V}$ and $V_{PP} = 12.75\text{ V}$ enters program mode. PROM can be verified by setting $V_{CC} = V_{PP} = 5.0\text{ V}$.

Programs can be written and verified using a general-purpose PROM writer and an adapter socket. Set the ROM type in the general-purpose PROM writer according to the following conditions. (Set the ROM type as equivalent to TC571000D).

- Size: 1 Mbit (128 K × 8 bit)
- V_{PP} : 12.75 V
- TPW: 0.1 ms
- Electric signature function: No

Figure 3.2 (1) shows the pin settings in PROM mode.

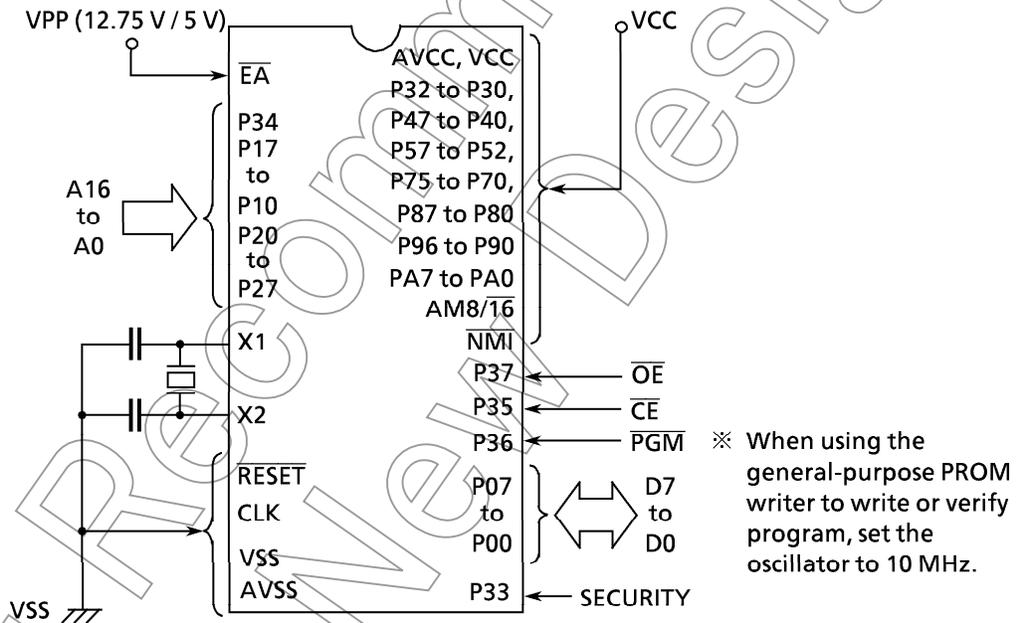


Figure 3.2 (1) PROM Mode Pin Settings

Electric Signature Cautions

TMP95PW64 does not support electric signature mode (hereafter called a signature). When a signature is used by a PROM writer, TMP95PW64 is damaged because 12 V ($\pm 0.5\text{ V}$) is applied to address pin 9 (A9). Therefore, use with the signature mode set off.

(2) Memory Map

The internal PROM addresses in PROM mode are 0000H to 1FFFFH. These correspond to MCU mode addresses FE0000H to FFFFFFFH.

Figure 3.2 (2) shows a comparison of the MCU and PROM mode memory maps.

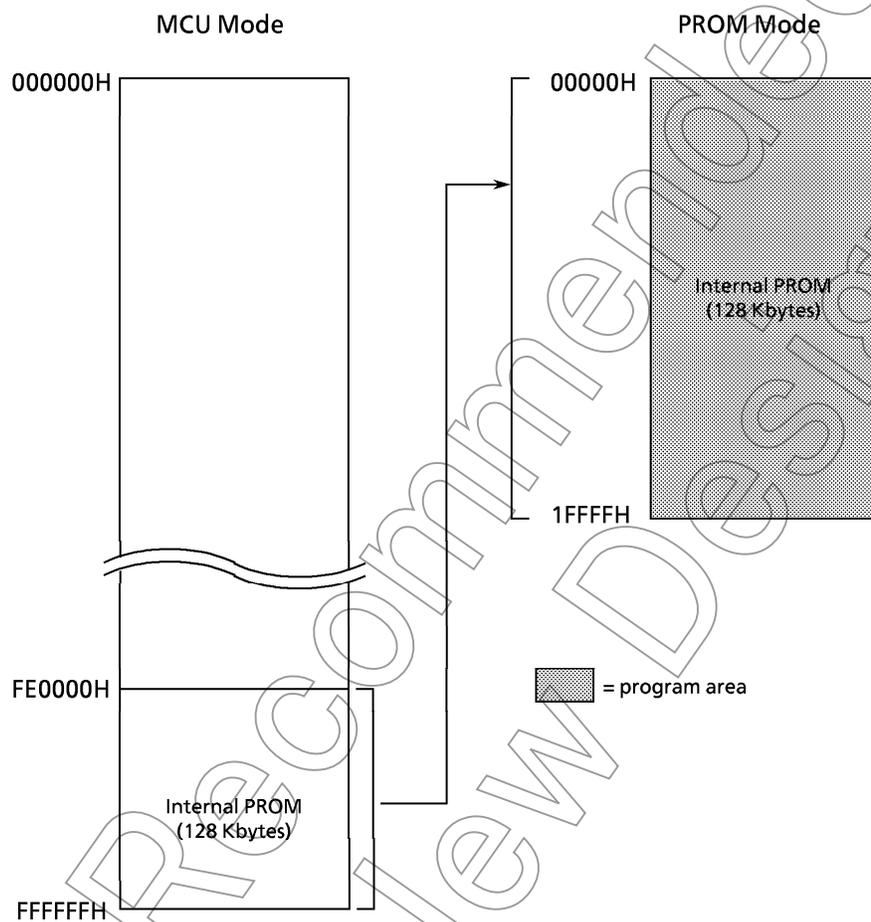


Figure 3.2 (2) Memory Map Comparison

(3) Program Mode

When TMP95PW64 is delivered, all bits are set to 1 (erased). Accordingly, program operations write 0 to the necessary bits. To enable writing, apply $V_{PP} = 12.75\text{ V}$, $\overline{OE} = V_{IH}$, $\overline{CE} = V_{HL}$. The internal one-time PROM can be written to in any order, or may be written only at specified addresses.

(4) Adaptor Socket (BM11129)

BM11129 is an adapter socket used to write data to the internal one-time PROM in TMP95PW64 using a general-purpose PROM writer.

(5) Settings for Writing Program Using General-Purpose PROM Writer

Use a PROM writer equivalent to the TC571000D PROM writer.

1. Set BM11129 (hereafter called the adapter) switch (SW1) to the program side (NOR). (Note 1)
2. Set TMP95PW64F to the adapter socket. (Note 2)
3. Set the adapter socket to the PROM writer. (Note 2)
4. Set the PROM writer PROM type to TC571000D.
5. Set the PROM write start address to 0000H and the end address to 1FFFFH. (Note 3)
6. Write to the internal one-time PROM and verify according to the PROM writer operating procedure.

Note 1: Writing data to the internal one-time PROM without setting the adapter switch (SW1) to the program side damages the device.

Note 2: Adaptor socket pin 1 should be aligned with PROM writer socket pin 1. Setting the two the wrong way round will damage the MCU or PROM writer.

Note 3: If data are written to addresses exceeding end address 1FFFFH, the data may be written to the 0000H to 1FFFFH addresses and program content may be damaged.

(6) High-Speed Programming Method

To enter program mode, apply $V_{PP}=12.75\text{ V}$ of program voltage with $V_{SS}=6.25\text{ V}$ and the $\overline{\text{RESET}}$ and CLK pins at low level input.

Input valid address and input data, and set $\overline{\text{CE}}$ to low level input. Data can be written by applying a 0.1ms program (single) pulse to the $\overline{\text{PGM}}$ input. Verify that data are written to each address. If data are not correctly written, again apply a 0.1ms program pulse, repeating this procedure (up to 25 times) until the data are correctly written. After that, write data in the same way, simply changing the addresses and the input data. When all writing is complete, set $V_{CC}=V_{PP}=5\text{ V}$ and verify all addresses.

Figure 3.2 (3) shows a writing flow chart.

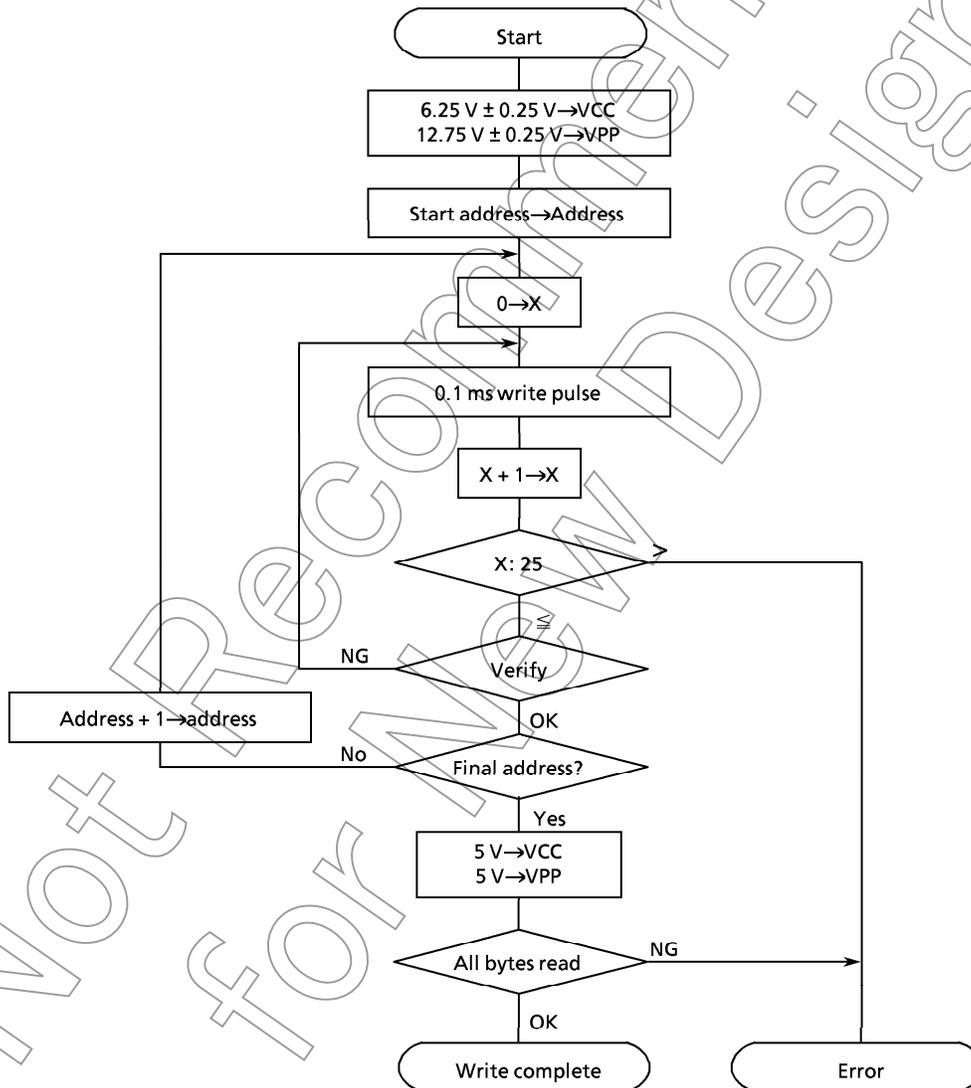


Figure 3.2 (3) Writing Flow Chart (High-Speed Programming Method)

(7) SECURITY Bit

The TMP95PW64 PROM cell contains a built-in security bit (one bit). Writing 0 to this security bit prevents the internal PROM data from being read in PROM mode.

Programming security bit

In PROM mode, set the security pin (P33) to 1 and write FEH to address 00000H. Set the PROM write start address to 00000H, the end address to 00000H, and the data on address 00000H to FEH. Then write FEH to address 00000H according to the PROM writer operating procedure. This sets the internal PROM security bit.

(8) Cautions

1. When turning the V_{PP} power supply (12.75 V) off and on, the V_{CC} must be on.
2. Do not plug in or unplug the device with the V_{PP} power on.
3. When executing the program, the voltage applied to the VPP pin should not exceed the maximum rating (14 V).

Not Recommended
for New Design

4. Electrical Characteristics

4.1 Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Power Supply Voltage	V_{CC}	-0.5 to +6.5	V
Input Voltage	V_{IN}	except for EA pin	-0.5 to $V_{CC} + 0.5$
		EA pin	-0.5 to 14.0
Output current (total)	ΣI_{OL}	+120	mA
Output current (total)	ΣI_{OH}	-120	mA
Power Dissipation ($T_a = +70^\circ\text{C}$)	P_D	600	mW
Soldering Temperature (10 s)	T_{SOLDER}	+260	$^\circ\text{C}$
Storage Temperature	T_{STG}	-65 to +150	$^\circ\text{C}$
Operating Temperature	T_{OPR}	-20 to +70	$^\circ\text{C}$

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

4.2 DC Electrical Characteristics

- (1)
- $V_{CC} = +5\text{ V} \pm 10\%$
- ,
- $T_a = -20$
- to
- $+70^\circ\text{C}$
- (
- $f_c = 8$
- to
- 25 MHz
-)

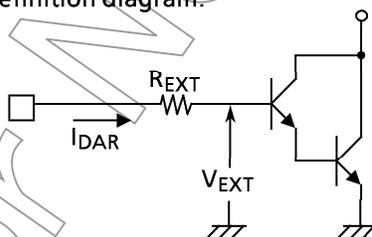
(Typical values are for $T_a = +25^\circ\text{C}$, $V_{CC} = +5\text{ V}$.)

Parameter	Symbol	Test Condition	Min	Max	Unit
Input Low Voltage (D0 to 15) Port 2 to A (except P56, P70, P72, P73, P75) RESET, NMI, INT0 to 4 EA, AM8/16 X1	V_{IL}		-0.3	0.8	V
	V_{IL1}		-0.3	0.3 V_{CC}	V
	V_{IL2}		-0.3	0.25 V_{CC}	V
	V_{IL3}		-0.3	0.3	V
Input High Voltage (D0 to 15) Port 2 to A (except P56, P70, P72, P73, P75) RESET, NMI, INT0 to 4 EA, AM8/16 X1	V_{IH}		2.2	$V_{CC} + 0.3$	V
	V_{IH1}		0.7 V_{CC}	$V_{CC} + 0.3$	V
	V_{IH2}		0.75 V_{CC}	$V_{CC} + 0.3$	V
	V_{IH3}		$V_{CC} - 0.3$	$V_{CC} + 0.3$	V
Output Low Voltage	V_{OL}	$I_{OL} = 1.6\text{ mA}$		0.45	V
	V_{OH}	$I_{OH} = -400\ \mu\text{A}$	2.4		V
Output High Voltage	V_{OH1}	$I_{OH} = -100\ \mu\text{A}$	0.75 V_{CC}		V
	V_{OH2}	$I_{OH} = -20\ \mu\text{A}$	0.9 V_{CC}		V
Darlington Drive Current (8 Output Pins max.)	I_{DAR}	$V_{EXT} = 1.5\text{ V}$ $R_{EXT} = 1.1\text{ k}\Omega$	-1.0	-3.5	mA
Input Leakage Current	I_{LI}	$0.0 \leq V_{in} \leq V_{CC}$	0.02 (Typ)	± 5	μA
Output Leakage Current	I_{LO}	$0.2 \leq V_{in} \leq V_{CC} - 0.2$	0.05 (Typ)	± 10	μA
Operating Current (RUN)	I_{CC}	$f_c = 25\text{ MHz}$	40 (Typ)	50	mA
IDLE2			30 (Typ)	40	mA
IDLE1			3.5 (Typ)	10	mA
STOP ($T_a = -20$ to $+70^\circ\text{C}$)		$0.2 \leq V_{in} \leq V_{CC} - 0.2$	0.5 (Typ)	50	μA
STOP ($T_a = 0$ to $+50^\circ\text{C}$)		$0.2 \leq V_{in} \leq V_{CC} - 0.2$		10	μA
Power Down Voltage (@STOP, RAM Back up)	V_{STOP}	$V_{IL2} = 0.2\ V_{CC}$, $V_{IH2} = 0.8\ V_{CC}$	2.0	6.0	V
Pull Up Resistance	R_{RP}		45	160	$\text{k}\Omega$
Pin Capacitance	C_{IO}	$f_c = 1\text{ MHz}$		10	pF
Schmitt Width RESET, NMI, INT0 to 4	V_{TH}		0.4	1.0 (Typ)	V

Note: I_{DAR} guarantees up to eight pins from any output port.

(2) $V_{CC} = +3 V \pm 10\%$, $T_a = -20$ to $+70^\circ\text{C}$ ($f_c = 4$ to 10 MHz)(Typical values are for $T_a = +25^\circ\text{C}$, $V_{CC} = +3 V$.)

Parameter	Symbol	Test Condition	Min	Max	Unit
Input Low Voltage (D0 to 15)	V_{IL}		-0.3	0.6	V
Port 2 to A (except P56, P70, P72, P73, P75)	V_{IL1}		-0.3	$0.3 V_{CC}$	V
RESET, NMI, INT0 to 4	V_{IL2}		-0.3	$0.25 V_{CC}$	V
EA, AM8/16	V_{IL3}		-0.3	0.3	V
X1	V_{IL4}		-0.3	$0.2 V_{CC}$	V
Input High Voltage (D0 to 15)	V_{IH}		2.0	$V_{CC} + 0.3$	V
Port 2 to A (except P56, P70, P72, P73, P75)	V_{IH1}		$0.7 V_{CC}$	$V_{CC} + 0.3$	V
RESET, NMI, INT0 to 4	V_{IH2}		$0.75 V_{CC}$	$V_{CC} + 0.3$	V
EA, AM8/16	V_{IH3}		$V_{CC} - 0.3$	$V_{CC} + 0.3$	V
X1	V_{IH4}		$0.8 V_{CC}$	$V_{CC} + 0.3$	V
Output Low Voltage	V_{OL}	$I_{OL} = 1.6$ mA		0.45	V
Output High Voltage	V_{OH}	$I_{OH} = -400$ μA	2.4		V
Input Leakage Current	I_{LI}	$0.0 \leq V_{in} \leq V_{CC}$	0.02 (Typ)	± 5	μA
Output Leakage Current	I_{LO}	$0.2 \leq V_{in} \leq V_{CC} - 0.2$	0.05 (Typ)	± 10	μA
Operating Current (RUN)	I_{CC}	$f_c = 10$ MHz	12 (Typ)	25	mA
IDLE2			4.5 (Typ)	17	mA
IDLE1			0.8 (Typ)	5	mA
STOP ($T_a = -20$ to $+70^\circ\text{C}$)		$0.2 \leq V_{in} \leq V_{CC} - 0.2$	0.5 (Typ)	50	μA
STOP ($T_a = 0$ to $+50^\circ\text{C}$)		$0.2 \leq V_{in} \leq V_{CC} - 0.2$		10	μA
Power Down Voltage (@ STOP, RAM Back up)	V_{STOP}	$V_{IL2} = 0.2 V_{CC}$, $V_{IH2} = 0.8 V_{CC}$	2.0	6.0	V
Pull Up Resistance	R_{RP}		70	400	k Ω
Pin Capacitance	C_{IO}	$f_c = 1$ MHz		10	pF
Schmitt Width RESET, NMI, INT0 to 4	V_{TH}		0.4	1.0 (Typ)	V

Refer: I_{DAR} definition diagram.

4.3 AC Electrical Characteristics

(1) $V_{CC} = +5\text{ V} \pm 10\%$, $T_a = -20$ to $+70^\circ\text{C}$

(fc = 8 MHz to 25 MHz)

No.	Parameter	Symbol	Formula		20 MHz		25 MHz		Unit
			Min	Max	Min	Max	Min	Max	
1	Oscillation cycle (= x)	t_{OSC}	40	125	50		40		ns
2	Clock pulse width	t_{CLK}	$2.0x - 40$		60		40		ns
3	A0 to 23 valid → Clock hold	t_{AK}	$0.5x - 20$		5		0		ns
4	Clock valid → A0 to 23 hold	t_{KA}	$1.5x - 60$		15		0		ns
5	A0 to 23 valid → $\overline{RD}/\overline{WR}$ fall	t_{AC}	$1.0x - 20$		30		20		ns
6	$\overline{RD}/\overline{WR}$ rise → A0 to 23 hold	t_{CA}	$0.5x - 20$		5		0		ns
7	A0 to 23 valid → D0 to 15 input	t_{AD}		$3.5x - 40$		135		100	ns
8	\overline{RD} fall → D0 to 15 input	t_{RD}		$2.5x - 45$		80		55	ns
9	\overline{RD} low pulse width	t_{RR}	$2.5x - 40$		85		60		ns
10	\overline{RD} rise → D0 to 15 hold	t_{HR}	0		0		0		ns
11	\overline{WR} low pulse width	t_{WW}	$2.5x - 40$		85		60		ns
12	D0 to 15 valid → \overline{WR} rise	t_{DW}	$2.0x - 40$		60		40		ns
13	\overline{WR} rise → D0 to 15 hold	t_{WD}	$0.5x - 10$		15		10		ns
14	A0 to 23 valid → \overline{WAIT} input	$t_{AW}^{(1, \overline{WAIT} + n \text{ mode})}$		$3.5x - 90$		85		50	ns
	A0 to 23 valid → \overline{WAIT} input	$t_{AW}^{(0 + n \overline{WAIT} \text{ mode})}$		$1.5x - 40$		35		20	ns
15	$\overline{RD}/\overline{WR}$ fall → \overline{WAIT} hold	$t_{CW}^{(1, \overline{WAIT} + n \text{ mode})}$	$2.5x + 0$		125		100		ns
	$\overline{RD}/\overline{WR}$ fall → \overline{WAIT} hold	$t_{CW}^{(0 + n \overline{WAIT} \text{ mode})}$	$0.5x + 0$		25		20		ns
16	\overline{WR} rise → PORT valid	t_{CP}		200		200		200	ns
17	\overline{CS} Low pulse width (PSRAM mode)	t_{CE}	$3.0x - 40$		110		80		ns
18	\overline{CS} fall → D0 to 15 input (PSRAM mode)	t_{CEA}		$3.0x - 60$		90		60	ns
19	Address setup time (PSRAM mode)	t_{PASC}	$0.5x - 15$		10		5		ns
20	\overline{CS} precharge time (PSRAM mode)	t_{PP}	$1.0x - 10$		40		30		ns

AC measuring conditions

- Output level: High 2.2 V/Low 0.8 V, $C_L = 50\text{ pF}$
- Input level: High 2.4 V / Low 0.45 V (D0 to D15)
High 0.8 Vcc / Low 0.2 Vcc (except for D0 to D15)

(2) $V_{CC} = +3V \pm 10\%$, $T_a = -20$ to $+70^\circ\text{C}$

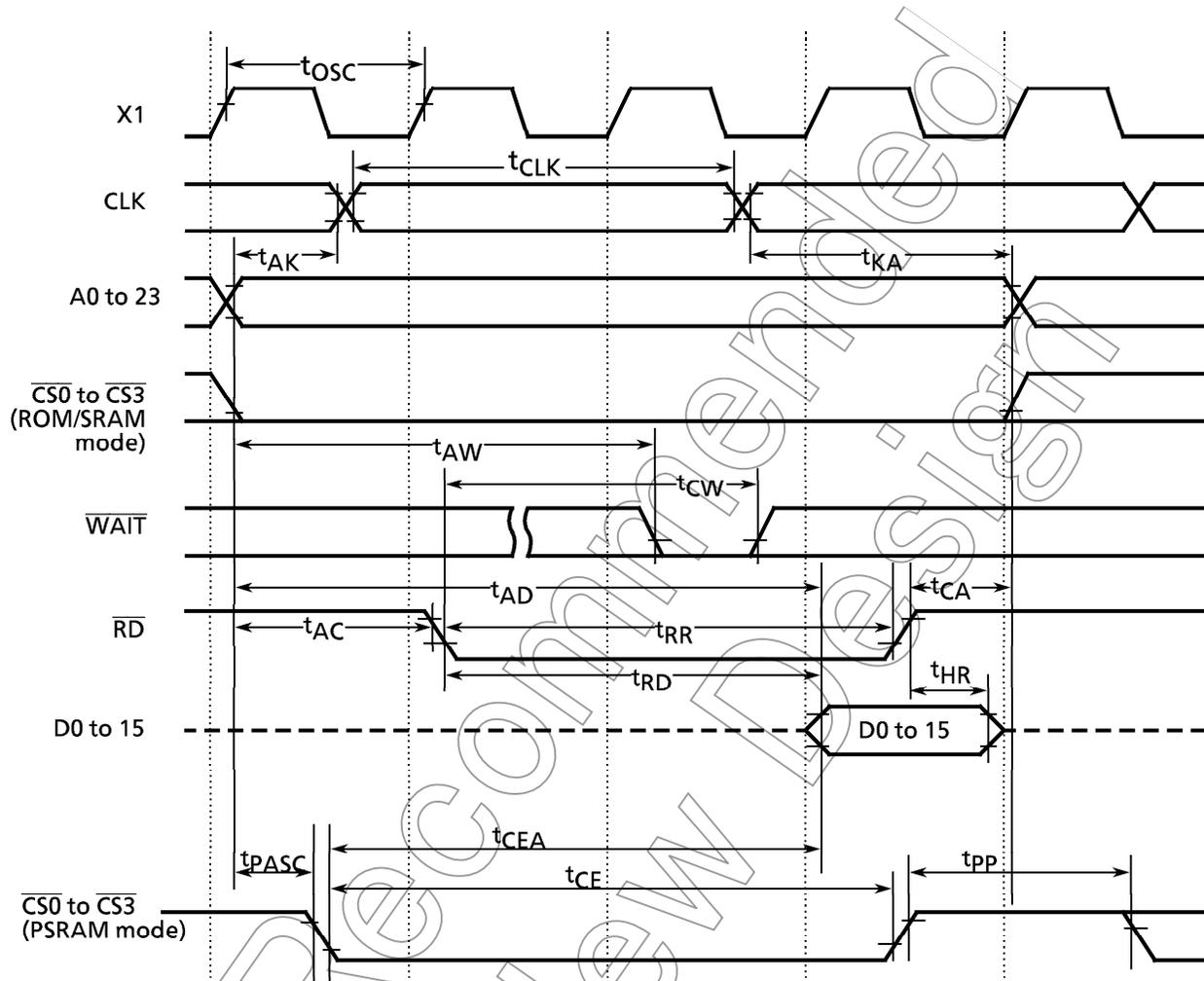
(fc = 4 MHz to 10 MHz)

No.	Parameter	Symbol	Formula		10 MHz		Unit
			Min	Max	Min	Max	
1	Oscillation cycle (= x)	t _{OSC}	100	250	100		ns
2	Clock pulse width	t _{CLK}	2.0x - 70		130		ns
3	A0 to 23 valid → RD/WR fall	t _{AC}	1.0x - 60		40		ns
4	RD/WR rise → A0 to 23 hold	t _{CA}	0.5x - 40		10		ns
5	A0 to 23 valid → D0 to 15 input	t _{AD}		3.5x - 125		225	ns
6	RD fall → D0 to 15 input	t _{RD}		2.5x - 115		135	ns
7	RD Low pulse width	t _{RR}	2.5x - 40		210		ns
8	RD rise → D0 to 15 hold	t _{HR}	0		0		ns
9	WR Low pulse width	t _{WW}	2.5x - 40		210		ns
10	D0 to 15 valid → WR rise	t _{DW}	2.0x - 120		80		ns
11	WR rise → D0 to 15 hold	t _{WD}	0.5x - 40		10		ns
12	A0 to 23 valid → WAIT input	t _{AW}	$\begin{matrix} (1 \\ + \\ n \\ \text{mode}) \\ \text{WAIT} \end{matrix}$	3.5x - 130		220	ns
	A0 to 23 valid → WAIT input	t _{AW}	$\begin{matrix} (0 + n \\ \text{mode}) \\ \text{WAIT} \end{matrix}$	1.5x - 80		70	ns
13	RD/WR fall → WAIT hold	t _{CW}	$\begin{matrix} (1 \\ + \\ n \\ \text{mode}) \\ \text{WAIT} \end{matrix}$	2.5x + 0		250	ns
	RD/WR fall → WAIT hold	t _{CW}	$\begin{matrix} (0 + n \\ \text{mode}) \\ \text{WAIT} \end{matrix}$	0.5x + 0		50	ns
14	WR rise → PORT valid	t _{CP}		200		200	ns
15	CS Low pulse width (PSRAM mode)	t _{CE}	3.0x - 70		230		ns
16	CS fall → D0 to 15 input (PSRAM mode)	t _{CEA}		3.0x - 160		140	ns
17	Address setup time (PSRAM mode)	t _{PASC}	0.5x - 30		20		ns
18	CS precharge time (PSRAM mode)	t _{PP}	1.0x - 40		60		ns

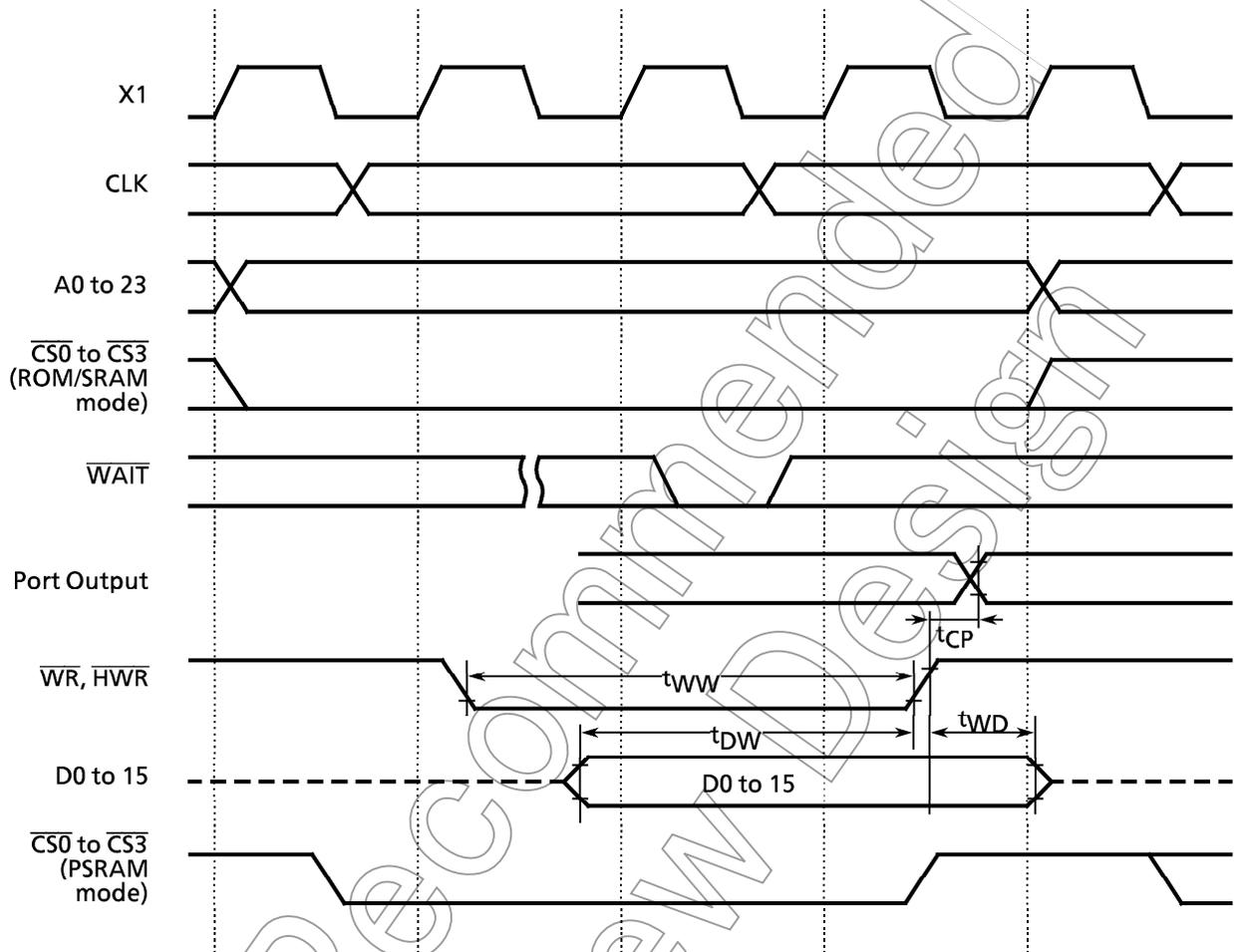
AC measuring conditions

- Output level: High 0.7x V_{CC} / Low 0.3x V_{CC}, C_L = 50 pF
- Input level: High 0.9x V_{CC} / Low 0.1x V_{CC}

(3) Read Cycle



(4) Write Cycle



Not Recommended for New Design

4.4 Serial Channel Timing

(1) I/O interface mode

① SCLK input mode

V_{CC} = +5 V ± 10%, T_a = -20 to +70°C (f_c = 8 to 25 MHz)
 V_{CC} = +3 V ± 10%, T_a = -20 to +70°C (f_c = 4 to 10 MHz)

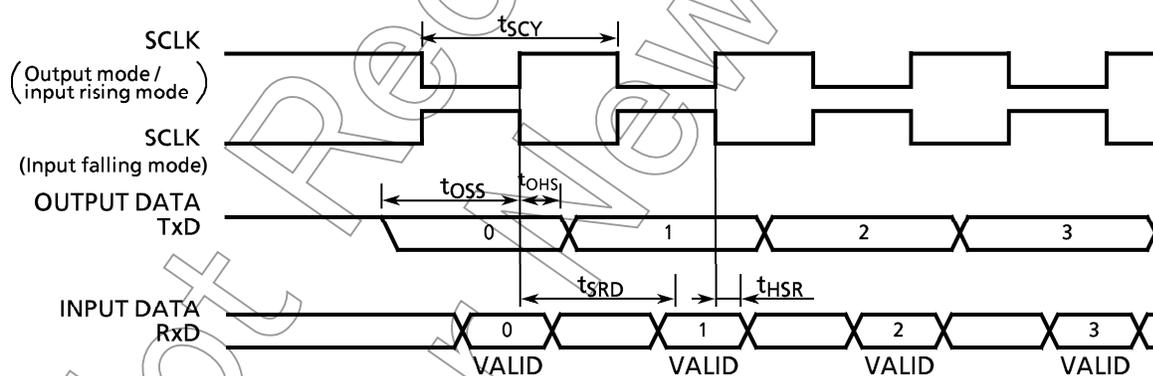
Parameter	Symbol	Formula		10 MHz		25 MHz		Unit
		Min	Max	Min	Max	Min	Max	
SCLK cycle	t _{SCY}	16x		1.6		0.64		μs
Output Data → SCLK rise/fall*	t _{OSS}	t _{SCY} /2 - 5x - 50		250		70		ns
SCLK rise/fall* → Output Data hold	t _{OHS}	5x - 100		400		100		ns
SCLK rise/fall* → input data hold	t _{HSR}	0		0		0		ns
SCLK rise/fall* → valid data input	t _{SRD}		t _{SCY} - 5x - 100		1000		340	ns

*) SCLK rise/fall: In SCLK rising edge mode, SCLK rising edge timing; in SCLK falling edge mode, SCLK falling edge timing

② SCLK output mode

V_{CC} = +5 V ± 10%, T_a = -20 to +70°C (f_c = 8 to 25 MHz)
 V_{CC} = +3 V ± 10%, T_a = -20 to +70°C (f_c = 4 to 10 MHz)

Parameter	Symbol	Formula		10 MHz		25 MHz		Unit
		Min	Max	Min	Max	Min	Max	
SCLK cycle (programmable)	t _{SCY}	16x	8192x	1.6	819.2	0.64	327.6	μs
Output Data → SCLK rising edge	t _{OSS}	t _{SCY} - 2x - 150		1250		410		ns
SCLK rising edge → Output Data hold	t _{OHS}	2x - 80		120		0		ns
SCLK rising edge → Input Data hold	t _{HSR}	0		0		0		ns
SCLK rising edge → valid data input	t _{SRD}		t _{SCY} - 2x - 150		1250		410	ns



(2) UART Mode (SCLK0 to 2 External Input)

V_{CC} = +5 V ± 10%, T_a = -20 to +70°C (f_c = 8 to 25 MHz)
 V_{CC} = +3 V ± 10%, T_a = -20 to +70°C (f_c = 4 to 10 MHz)

Parameter	Symbol	Formula		10 MHz		25 MHz		Unit
		Min	Max	Min	Max	Min	Max	
SCLK cycle	t _{SCY}	4x + 20		420		180		ns
Low-level SCLK pulse width	t _{SCYL}	2x + 5		205		85		ns
High-level SCLK pulse width	t _{SCYH}	2x + 5		205		85		ns

4.5 A/D Conversion Characteristics

V_{CC} = +5 V ± 10%, T_a = -20 to +70°C (f_c = 8 to 25 MHz)V_{CC} = +3 V ± 10%, T_a = -20 to +70°C (f_c = 4 to 10 MHz)

Parameter		Symbol	Test Conditions	Min	Typ	Max	Unit
A/D analog reference supply voltage (+)		V _{REFH}		V _{CC} - 0.2		V _{CC}	V
A/D analog reference supply voltage (-)		V _{REFL}		V _{SS}		V _{SS} + 0.2	
Analog reference voltage		AV _{CC}		V _{CC} - 0.2		V _{CC}	
Analog reference voltage		AV _{SS}		V _{SS}		V _{SS} + 0.2	
Analog input voltage		V _{AIN}		V _{REFL}		V _{REFH}	
Analog reference voltage supply current	<VREFON> = 1	I _{REF}	V _{CC} = 5 V ± 10%			3.7	mA
			V _{CC} = 3 V ± 10%			2.2	
	<VREFON> = 0		V _{CC} = 2.7 to 5.5 V		0.02		5.0
Total tolerance (excludes quantization error)		E _T	V _{CC} = 5 V ± 10%		± 1	± 3	LSB
			V _{CC} = 3 V ± 10%		± 1	± 3	

Note 1: 1LSB = (V_{REFH} - V_{REFL}) / 2¹⁰ [V]Note 2: Power supply current I_{CC} from the V_{CC} pin includes the power supply current from the AV_{CC} pin.

4.6 D/A Conversion Characteristics

V_{CC} = +5 V ± 10%, T_a = -20 to +70°C (f_c = 8 to 25 MHz)V_{CC} = +3 V ± 10%, T_a = -20 to +70°C (f_c = 4 to 10 MHz)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Analog reference voltage	AV _{CC}		V _{CC} - 0.2		V _{CC}	V
Analog reference voltage	AV _{SS}		V _{SS}		V _{SS} + 0.2	
Total tolerance		R = 1 MΩ (Note)			7.0	LSB
		R = 5 MΩ (Note)			4.0	LSB
		R = 10 MΩ (Note)			3.5	LSB
Differential linear error				2.0		LSB

Note: R is the external load resistance on the D/A converter output pin (DAOUT0, DAOUT1).

4.7 Event Counter (External Input Clocks: T10, T14, T18, T19, T1A, T1B)

V_{CC} = +5 V ± 10%, T_a = -20 to +70°C (f_c = 8 to 25 MHz)V_{CC} = +3 V ± 10%, T_a = -20 to +70°C (f_c = 4 to 10 MHz)

Parameter	Symbol	Calculator		10 MHz		25 MHz		Unit
		Min	Max	Min	Max	Min	Max	
External input clock cycle	t _{VCK}	8x + 100		900		420		ns
External low-level input clock pulse width	t _{VCKL}	4x + 40		440		200		ns
External high-level input clock pulse width	t _{VCKH}	4x + 40		440		200		ns

4.8 Interrupt Operation

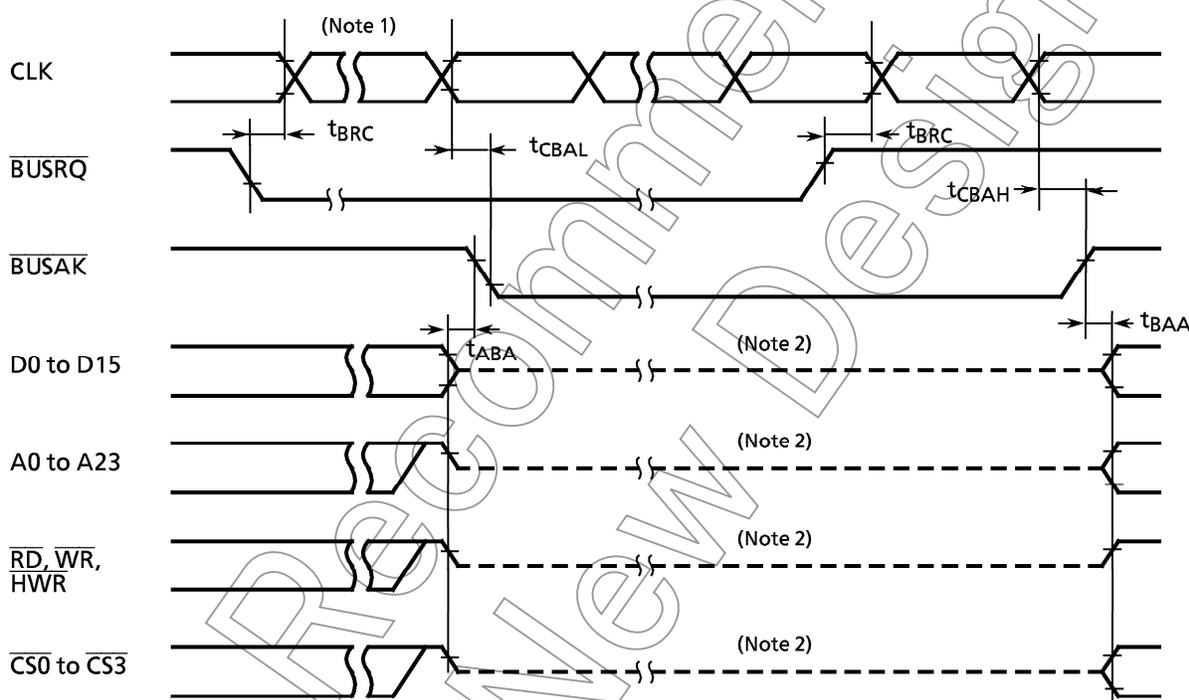
V_{CC} = +5 V ± 10%, T_a = -20 to +70°C (f_c = 8 to 25 MHz)V_{CC} = +3 V ± 10%, T_a = -20 to +70°C (f_c = 4 to 10 MHz)

Parameter	Symbol	Calculator		10 MHz		25 MHz		Unit
		Min	Max	Min	Max	Min	Max	
NMI, INT0 to 4 low-level pulse width	t _{INTAL}	4x		400		160		ns
NMI, INT0 to 4 high-level pulse width	t _{INTAH}	4x		400		160		ns
INT5 to INT8 low-level pulse width	t _{INTBL}	8x + 100		900		420		ns
INT5 to INT8 high-level pulse width	t _{INTBH}	8x + 100		900		420		ns

4.9 Bus Request/Bus Acknowledge Timing

V_{CC} = +5 V ± 10%, T_a = -20 to +70°C (f_c = 8 to 25 MHz)
 V_{CC} = +3 V ± 10%, T_a = -20 to +70°C (f_c = 4 to 10 MHz)

Parameter	Symbol	Calculator		10 MHz		25 MHz		Unit
		Min	Max	Min	Max	Min	Max	
BUSRQ setup time for CLK	t _{BRC}	120		120		120		ns
CLK → BUSAK fall	t _{CBAL}		2.0x + 120		320		200	ns
CLK → BUSAK rise	t _{CBAH}		0.5x + 40		90		60	ns
Time from output buffer off until BUSAK falling edge	t _{ABA}	0	80	0	80	0	80	ns
Time from BUSAK rising edge until output buffer on	t _{BAA}	0	80	0	80	0	80	ns



Note 1: When BUSRQ goes to low level to request bus release, if the current bus cycle is yet complete due to a wait, the bus is not released until the wait completes.

Note 2: The dotted line indicates only that the output buffer is off, not that the signal is at middle level. Immediately after bus release, the signal level prior to the bus release is held dynamically by the external load capacitance. Therefore, designs should allow for the fact that when using an external resistor or similar to fix the signal level while the bus is released, after bus release a delay occurs before the signal goes to its fixed level (due to the CR time constant). The internal programmable pull-up resistor continues to function in accordance with the internal signal level.

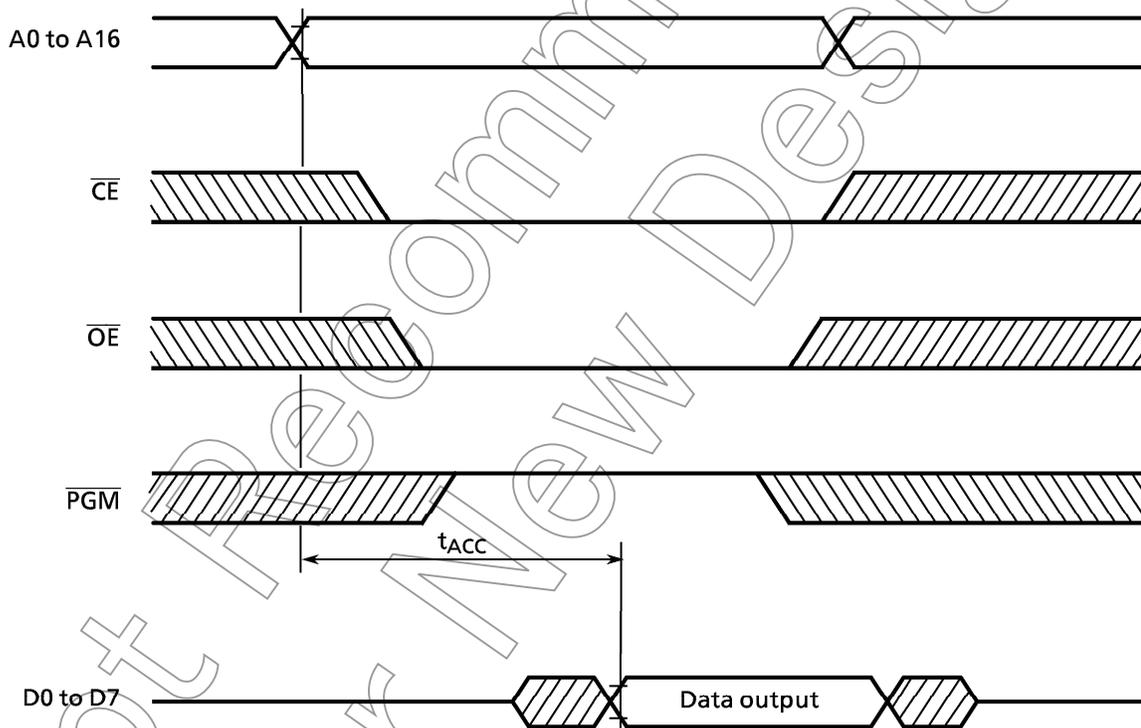
4.10 Read Operations in PROM Mode

DC / AC Electrical Specifications

Ta = 25 ± 5°C, Vcc = 5 V ± 10%

Parameter	Symbol	Test Condition	Min	Max	Unit
V _{pp} Read Voltage	V _{PP}		4.5	5.5	V
Input High Voltage (A0 to A16, \overline{CE} , \overline{OE} , PGM)	V _{IH}		2.2	V _{CC} + 0.3	V
Input Low Voltage (A0 to A16, \overline{CE} , \overline{OE} , PGM)	V _{IL}		-0.3	0.8	V
Address to Output Delay	t _{ACC}	C _L = 50 pF	-	2.25TCYC + α	ns

TCYC = 400 ns (10 MHz Clock)
α = 200 ns

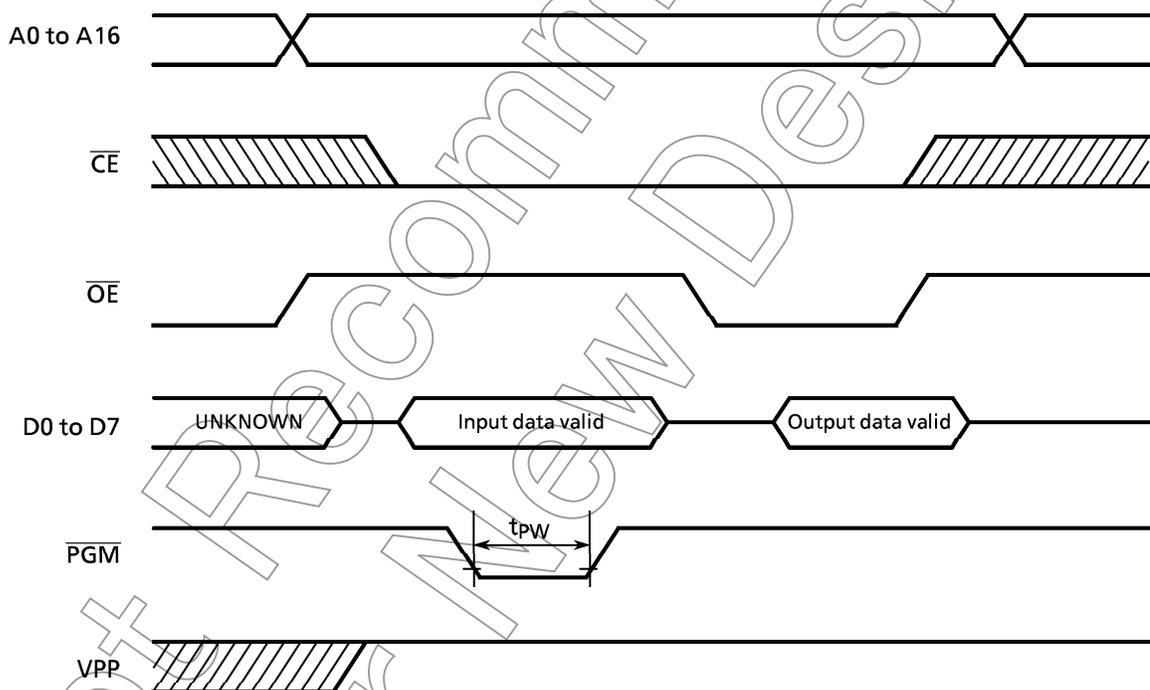


4.11 Program Operations in PROM Mode

DC / AC Electrical Specifications

Ta = 25 ± 5°C, Vcc = 6.25 V ± 0.25 V

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Programing Supply Voltage	V _{PP}		12.50	12.75	13.00	V
Input High Voltage (D0 to D7, A0 to A16, \overline{CE} , \overline{OE} , \overline{PGM})	V _{IH}		2.6		V _{CC} + 0.3	V
Input Low Voltage (D0 to D7, A0 to A16, \overline{CE} , \overline{OE} , \overline{PGM})	V _{IL}		-0.3		0.8	V
V _{CC} Supply Current	I _{CC}	f _c = 10 MHz	-		50	mA
V _{PP} Supply Current	I _{PP}	V _{PP} = 13.00 V	-		50	mA
\overline{PGM} Program Pulse Width	t _{PW}	C _L = 50 pF	0.095	0.1	0.105	ms



Note 1: When turning the V_{PP} (12.75 V) power supply off and on, ensure that V_{CC} is on.

Note 2: Do not plug in or unplug the device when the V_{PP} power (12.75 V) is on.
(This can damage the device.)

Note 3: The V_{PP} pin maximum rating is 14 V. When the program is executed, the voltage applied, including overshoot, should not exceed 14 V.

Not Recommended
for New Design